



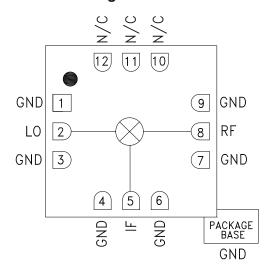
GaAs MMIC FUNDAMENTAL MIXER, 11 - 20 GHz

Typical Applications

The HMC554LC3B is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios & VSAT
- Test Equipment & Sensors
- Military End-Use

Functional Diagram



Features

High LO/RF Isolation: 46 dB

Passive Double Balanced Topology

Low Conversion Loss: 7 dB

Wide IF Bandwidth: DC - 6 GHz

Robust 1,000V ESD, Class 1C

12 Lead Ceramic 3x3mm SMT Package: 9mm²

General Description

The HMC554LC3B is a general purpose double balanced mixer in a leadless RoHS compliant SMT package that can be used as an upconverter or downconverter between 11 and 20 GHz. This mixer is fabricated in a GaAs MESFET process, and requires no external components or matching circuitry. The HMC554LC3B provides excellent LO to RF and LO to IF isolation due to optimized balun structures. The RoHS compliant HMC554LC3B eliminates the need for wire bonding, and is compatible with high volume surface mount manufacturing techniques.

Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, IF= 100 MHz, LO= +13 dBm*

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range, RF & LO		12 - 16		11 - 20		GHz	
Frequency Range, IF	DC - 6		DC - 6			GHz	
Conversion Loss		7	9		8	11	dB
Noise Figure (SSB)		7	9		8	11	dB
LO to RF Isolation	40	46		40	46		dB
LO to IF Isolation	34	40		30	40		dB
RF to IF Isolation	18	25		15	25		dB
IP3 (Input)		18			18		dBm
IP2 (Input)		48			45		dBm
1 dB Gain Compression (Input)		11			11		dBm

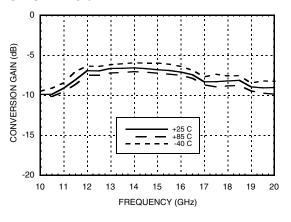
^{*}Unless otherwise noted, all measurements performed as downconverter, IF= 100 MHz.



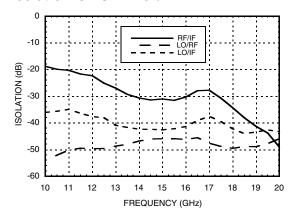


GaAs MMIC FUNDAMENTAL MIXER, 11 - 20 GHz

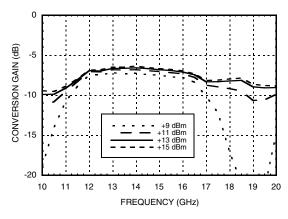
Conversion Gain vs. Temperature @ LO = +13 dBm



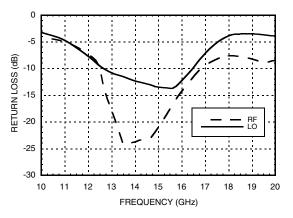
Isolation @ LO = +13 dBm



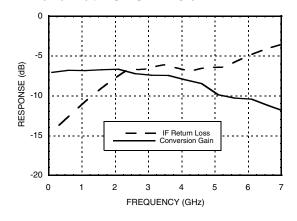
Conversion Gain vs. LO Drive



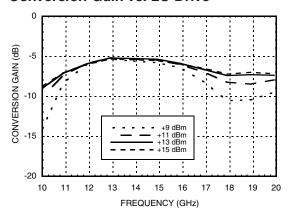
Return Loss @ LO = +13 dBm



IF Bandwidth @ LO = +13 dBm



Upconverter Performance Conversion Gain vs. LO Drive

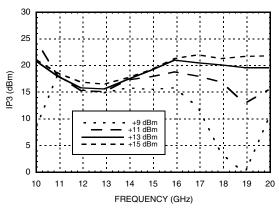




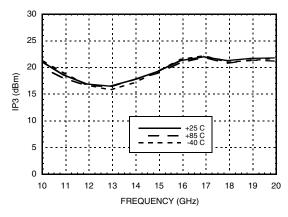


GaAs MMIC FUNDAMENTAL MIXER, 11 - 20 GHz

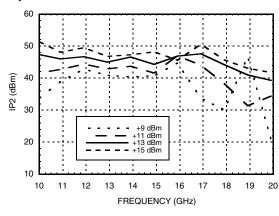
Input IP3 vs. LO Drive *



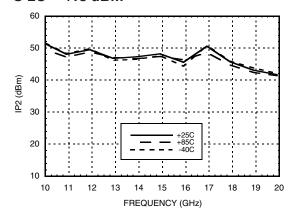
Input IP3 vs. Temperature @ LO = +13 dBm*



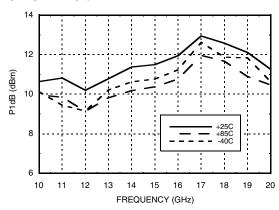
Input IP2 vs. LO Drive *



Input IP2 vs. Temperature @ LO = +13 dBm*



Input P1dB vs. Temperature @ LO = +13 dBm



MxN Spurious Outputs

	nLO				
mRF	0	1	2	3	4
0	xx	19	25	xx	xx
1	29	0	51	55	xx
2	81	85	60	88	104
3	xx	97	98	76	99
4	xx	xx	105	98	105

RF = 15.1 GHz @ -10 dBm LO = 15.0 GHz @ +13 dBm

All values in dBc below the IF output power level.

^{*} Two-tone input power = -10 dBm each tone, 1 MHz spacing.





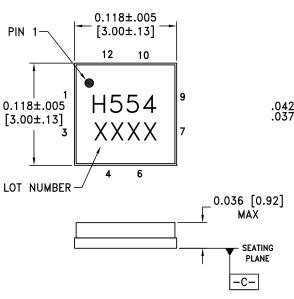
GaAs MMIC FUNDAMENTAL MIXER, 11 - 20 GHz

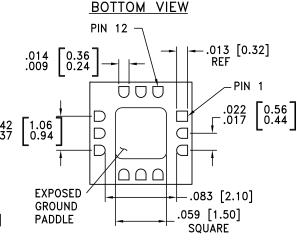
Absolute Maximum Ratings

RF / IF Input	+25 dBm
LO Drive	+25 dBm
Channel Temperature	150 °C
Continuous Pdiss (T= 85 °C) (derate 2.32 mW/°C above 85 °C)	150 mW
Thermal Resistance (channel to ground paddle)	431 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1C



Outline Drawing





NOTES:

- 1. PACKAGE BODY MATERIAL: ALUMINA.
- 2. LEAD AND GROUND PADDLE PLATING: 30-80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL.
- 3. DIMENSIONS ARE IN INCHES (MILLIMETERS).
- 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 5. CHARACTERS TO BE HELVETICA MEDIUM, .025 HIGH, BLACK INK, OR LASER MARK LOCATED APPROX. AS SHOWN.
- 6. PACKAGE WARP SHALL NOT EXCEED 0.05MM DATUM C -
- 7. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC554LC3B	Alumina, White	Gold over Nickel	MSL3 ^[1]	H554 XXXX

^[1] Max peak reflow temperature of 260 °C

^{[2] 4-}Digit lot number XXXX





GaAs MMIC FUNDAMENTAL MIXER, 11 - 20 GHz

Pin Descriptions

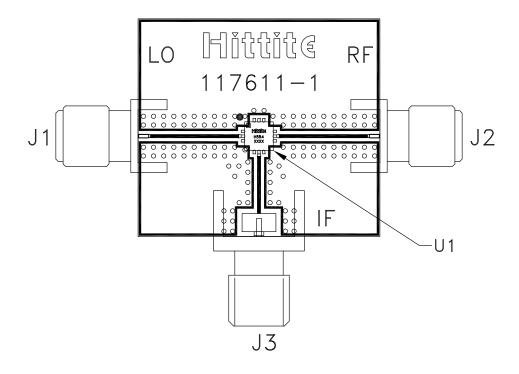
Pin Number	Function	Description	Interface Schematic
1, 3, 4, 6, 7, 9	GND	Package bottom must also be connected to RF/DC ground.	GND
2	LO	This pin is DC coupled and matched to 50 Ohms.	LO 0————————————————————————————————————
5	IF	This pin is DC coupled. For applications not requiring operation to DC, this port should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary IF frequency range. For operation to DC, this pin must not source or sink more than 2 mA of current or part non-function and possible part failure will result.	IFO THE STATE OF T
8	RF	This pin is DC coupled and matched to 50 Ohms.	RF O
10, 11, 12	N/C	No connection required. These pins may be connected to RF/DC ground without affecting performance.	





GaAs MMIC FUNDAMENTAL MIXER, 11 - 20 GHz

Evaluation PCB



List of Materials for Evaluation PCB 109952 [1]

Item	Description
J1 - J2	SRI SMA Connector
J3	Johnson SMA Connector
U1	HMC554LC3B Mixer
PCB [2]	117611 Evaluation PCB

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

^[2] Circuit Board Material: Arlon 25 FR